



SWTEST

PROBE TODAY, FOR TOMORROW

**A FULLY AUTOMATIC ELECTRO-OPTICAL TEST SYSTEM
ENABLING THE DEVELOPMENT OF A SILICON PHOTONICS
TECHNOLOGY PLATFORM**

Jeroen De Coster, Rafal Magdziak,
Peter De Heyn, Erik Jan Marinissen,
Marianna Pantouvaki, Joris Van
Campenhout, Philippe Absil

Dan Rishavy, Joe Frankel,
Kainoa Kekahuna, Kazuki Negishi,
Mike Simmons, Eric Christenson



Leuven, Belgium



Beaverton, OR, USA

June 2-5, 2019

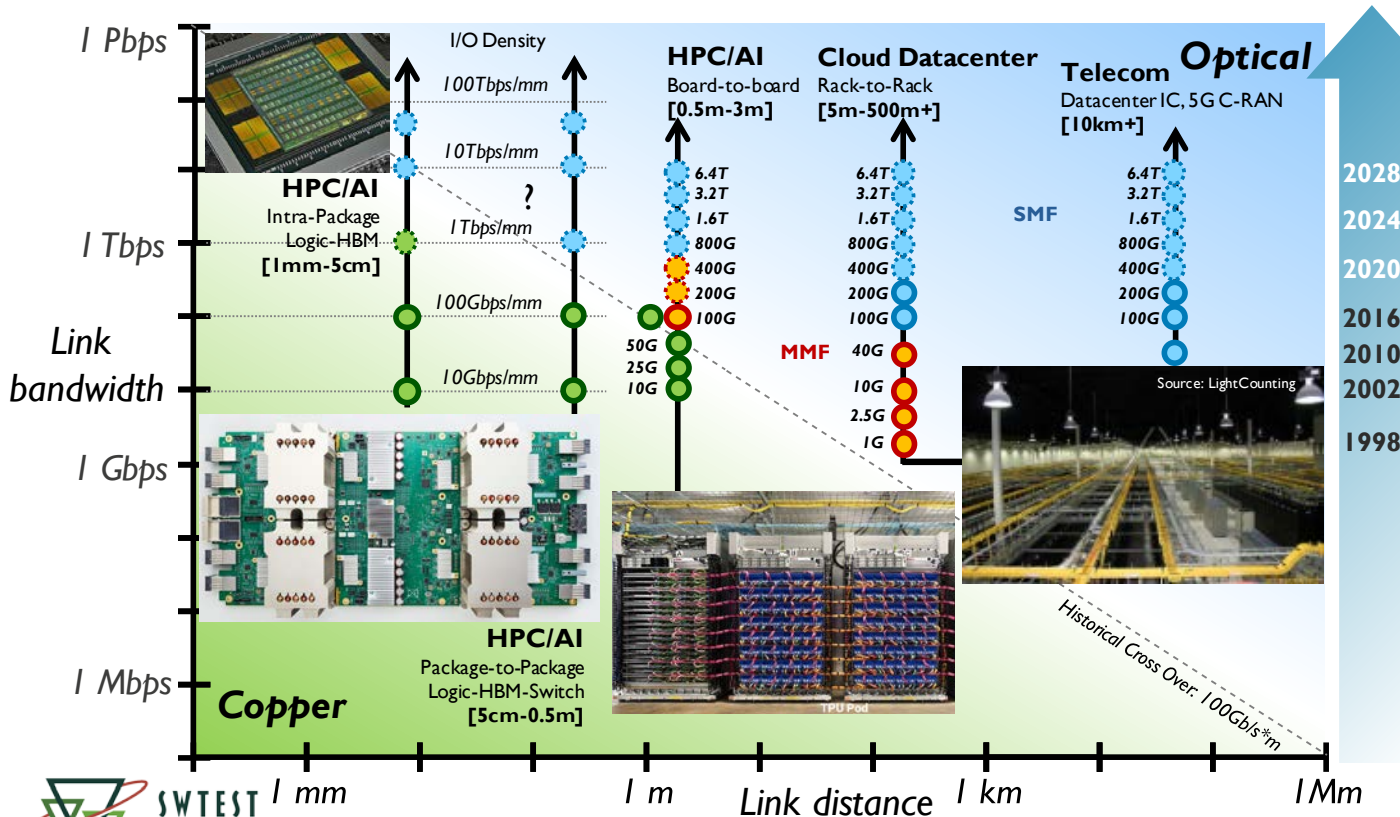
PUBLIC

OUTLINE

- What are we developing:
 - Silicon photonics platform
- What do we want to measure?
 - Platform-specific device parameters
- How do we measure
 - Baseline flow, test hardware
 - Python test executive
- Working in the CR environment
- Data analysis and reporting
- Setup monitoring
- Conclusion

OPTICAL INTERCONNECT LANDSCAPE

OPTICAL LINKS REPLACING ELECTRICAL LINKS AT PROGRESSIVELY SHORTER INTERCONNECT DISTANCES



Terabit-Scale Optical Interconnectivity will be needed by **early 2020's**

Optical Interconnects will move **into the rack (<3m)**

Total Optical Transceiver Volume expected to increase **>>10x**

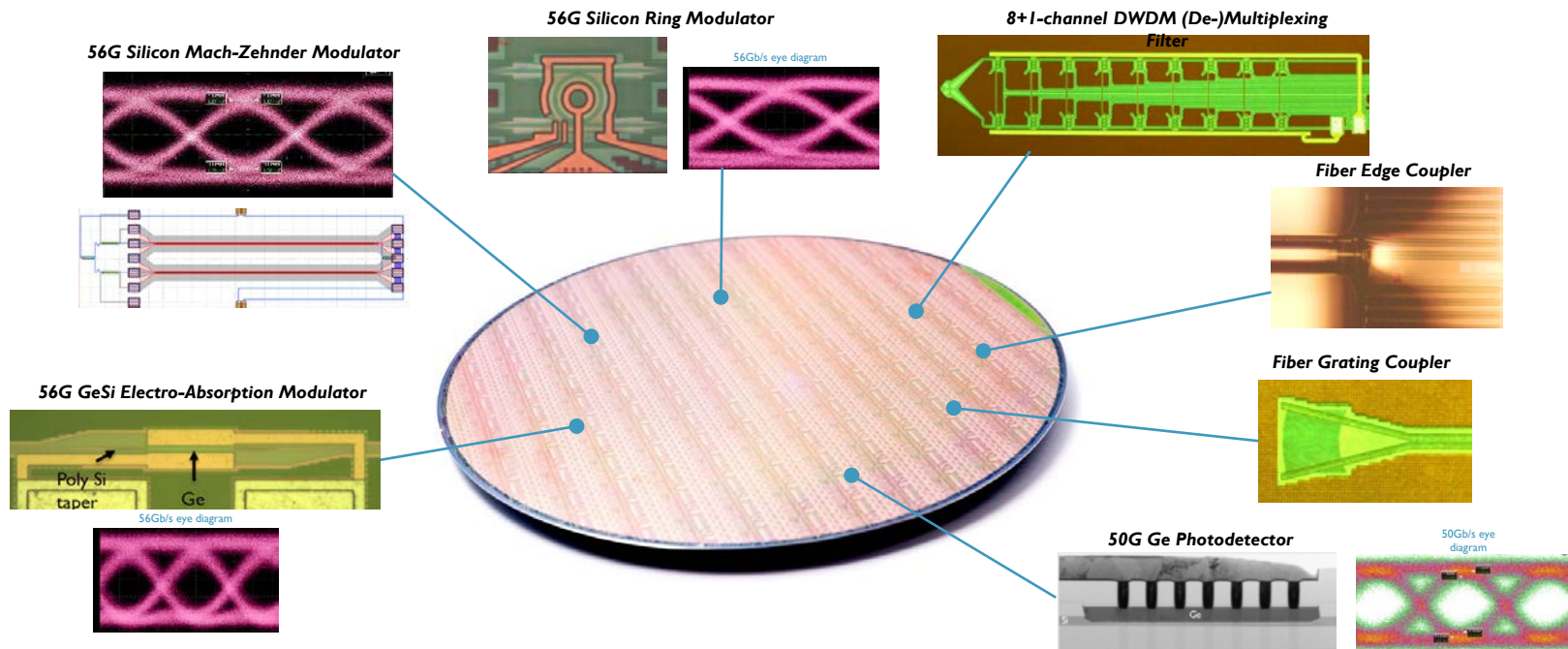
Objective:
Develop a **Silicon Photonic Integration Platform** for **Optical Interconnect Scaling** at all link distances.

2028
2024
2020
2016
2010
2002
1998

What are we developing

IMEC'S 50G SILICON PHOTONICS PLATFORM

FULLY INTEGRATED 50GB/S NRZ, WDM SI PHOTONICS TECHNOLOGY

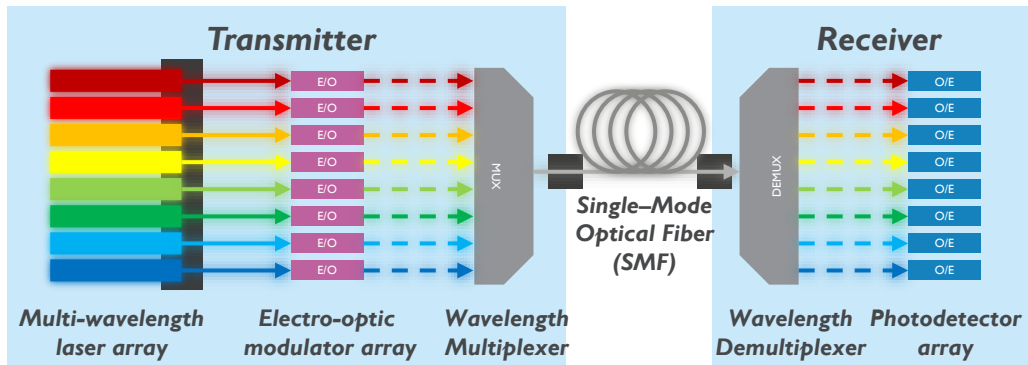


- Co-integration of the 50Gb/s building blocks in a single platform based on CMOS090
- Supports all dominant Si Photonics transceiver concepts pursued in industry & academia
- Available on 200mm [iSiPP200], under development on 300mm [iSiPP300]
- Based on 220nm Silicon / 2000nm BoX SOI wafers

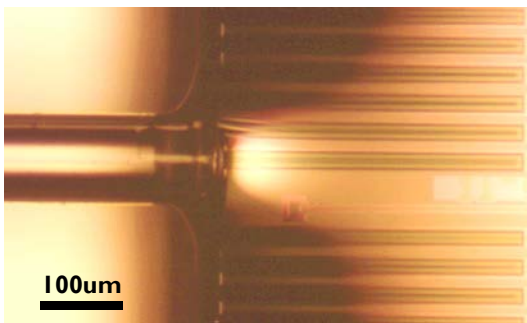
What are we developing

WAFER LEVEL TESTING

FIBER AND LASER COUPLING STRUCTURES

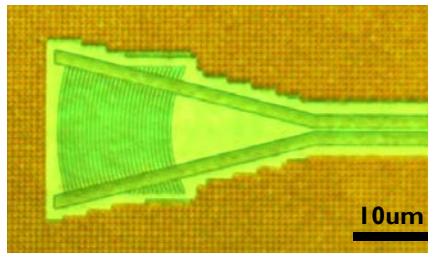


In-Plane Coupler

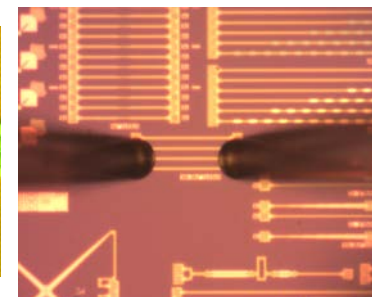


<2dB loss over 100nm+

Surface-Normal Grating Coupler



<3dB loss over 30nm



WHAT DO WE WANT TO MEASURE

PROCESS CONTROL MONITORING

- Monitor technology-specific parameters
- Observe impact of process splits on these parameters during development of the technology platform

Component		Test sites	
Passive		Grating couplers	Insertion loss, bandwidth, peak wavelength
O-band <i>1310nm</i>	C-band <i>1550nm</i>	Waveguide spirals	Propagation loss, bend loss
		Crossings	Insertion loss, cross-talk
		Transitions	Insertion loss
		Directional coupling	Power coupling, excess loss
		Splitters	Insertion loss, excess loss
		Active	Germanium photo diode
O-band <i>1310nm</i>	C-band <i>1550nm</i>	Mach-Zehnder interferometer	Insertion loss, V_{pi}
		Phase shifter loss	Propagation loss

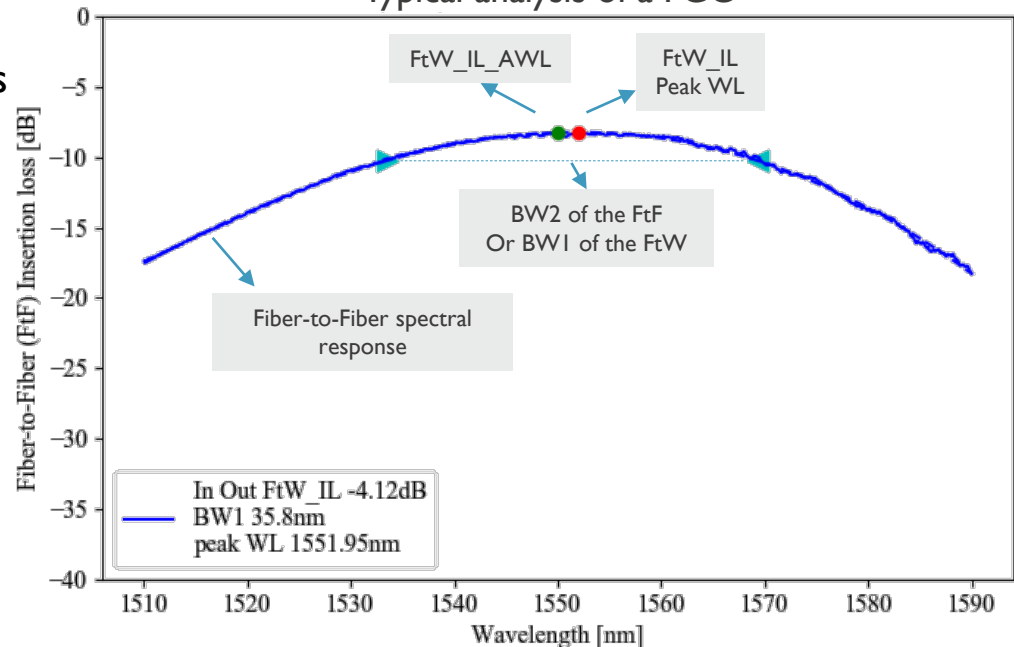
What do we want to measure

PROCESS CONTROL MONITOR STRUCTURES

FIBER GRATING COUPLER (FGC) PERFORMANCE

- A straight waveguide with a grating coupler on both ends
- Measured quantity: wavelength dependent insertion loss, fiber to fiber
- Extracted device parameters
 - Fiber-to-waveguide insertion loss
 FtW_IL_AWL [dB]
 - Peak wavelength
 PWL [nm]
 - Peak wavelength IL
 FtW_IL [dB]
 - 1 dB bandwidth
 $BW1$ [nm]

Typical analysis of a FGC

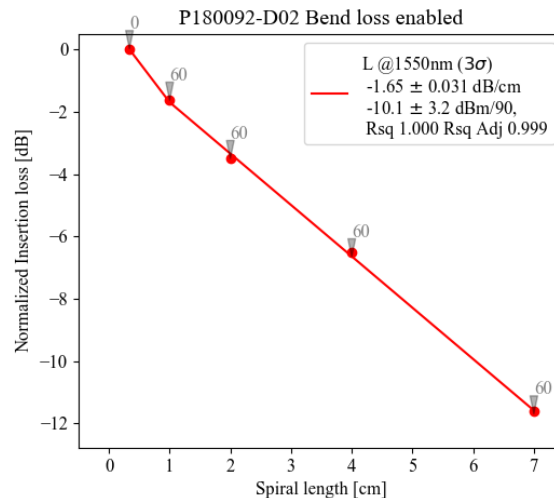
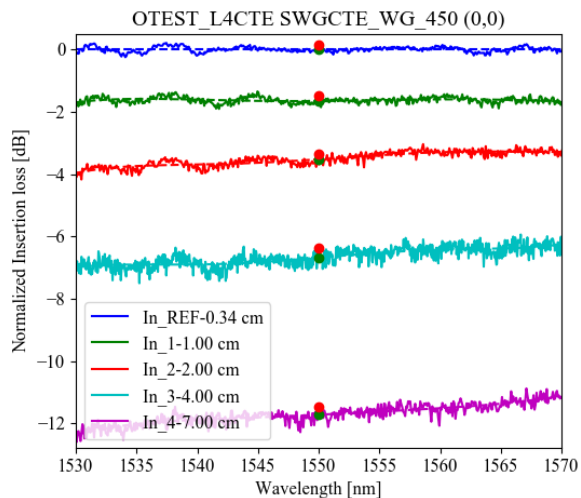
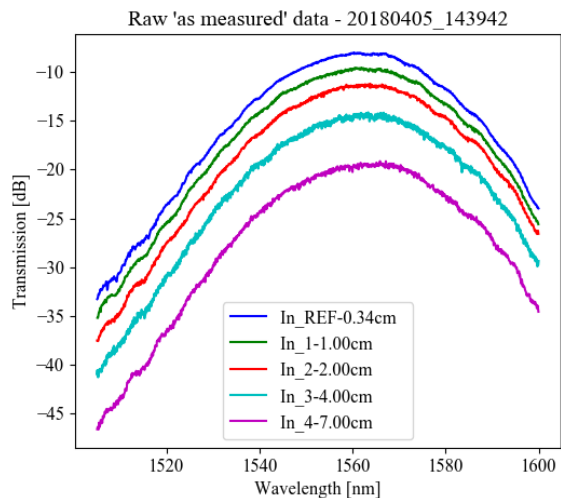


What do we want to measure

PROCESS CONTROL MONITOR STRUCTURES

PROPAGATION LOSS TEST

- A set of (spiral) waveguides with increasing lengths L , #bends
- Measured quantity: wavelength dependent loss vs. length
- Linear regression of IL vs L , #bends to obtain propagation and bend loss

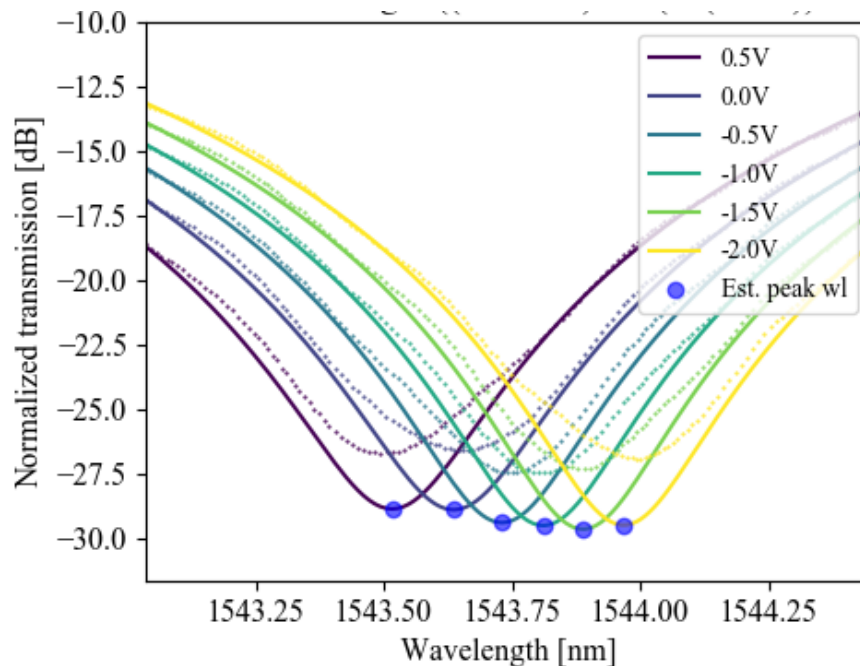
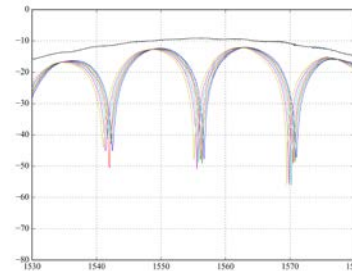


What do we want to measure

PROCESS CONTROL MONITOR STRUCTURES

MODULATOR TEST

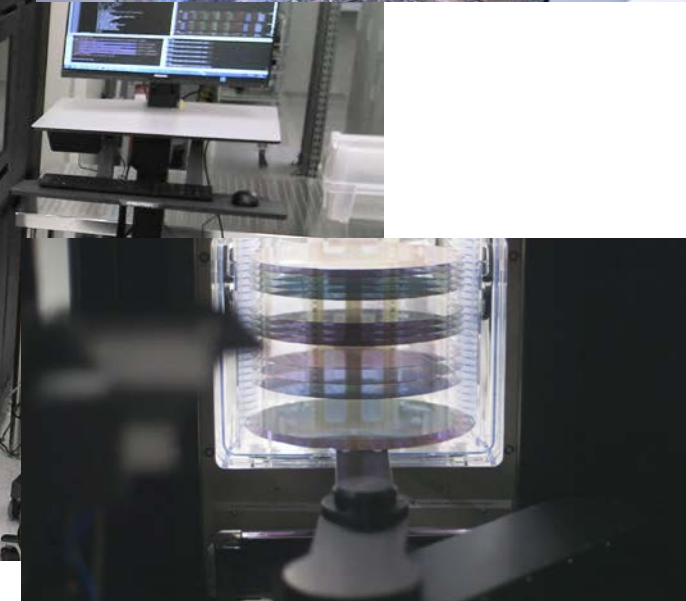
- Measured quantity: IV, wavelength dependent loss vs. DC bias
- Spectral response fitted with raised cosine
 - Data (dotted line)
 - Fit (solid line)
- Parameters extracted:
 - Insertion loss
 - Modulation efficiency V_{π}



How do we measure

THOR TEST SYSTEM IN IMEC'S 200mm FAB

FORMFACTOR CM300xi-SiPh PROBE STATION WITH SiPh-



AUTONOMOUS SiPh MEASUREMENT ASSISTANT FOR CM300xi

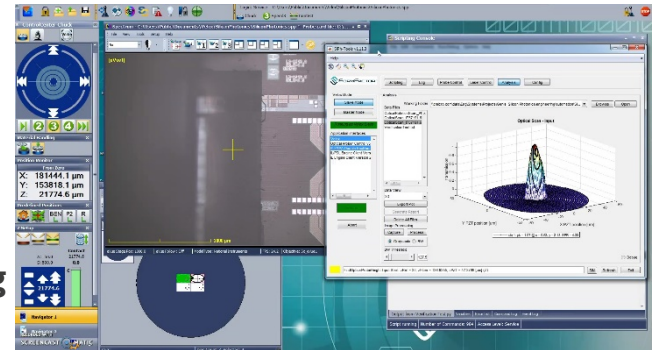


Positioning and Z Displacement Control

Integrated and Validated Single or Dual Sided 6 Axis Automated Positioning

- FFI On-site warranty and spares
- Interchangeable Fiber Arm
- Single Fiber or Array Holders
- Integrated Z Displacement
- Integrated Illumination
- Calibration Kit
- Integration Kit

SiPh-Tools: Automated Calibrations and Alignments



FormFactor's Cascade CM300xi Probe Station
Highly Stable and Robust Platform for Optical/Electrical Probing

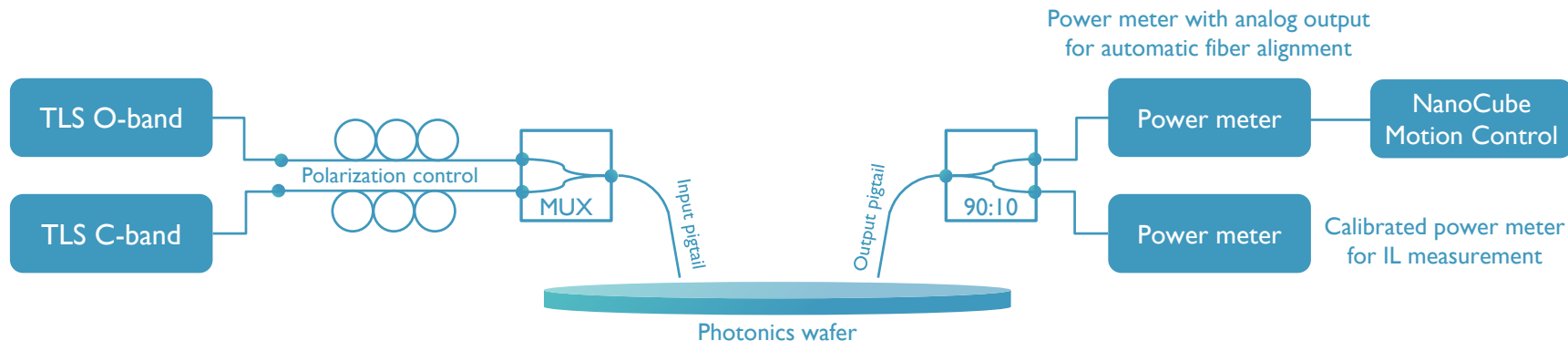


How do we measure

THOR TEST SYSTEM

SCHEMATIC LAYOUT OF THE OPTICAL PATHS

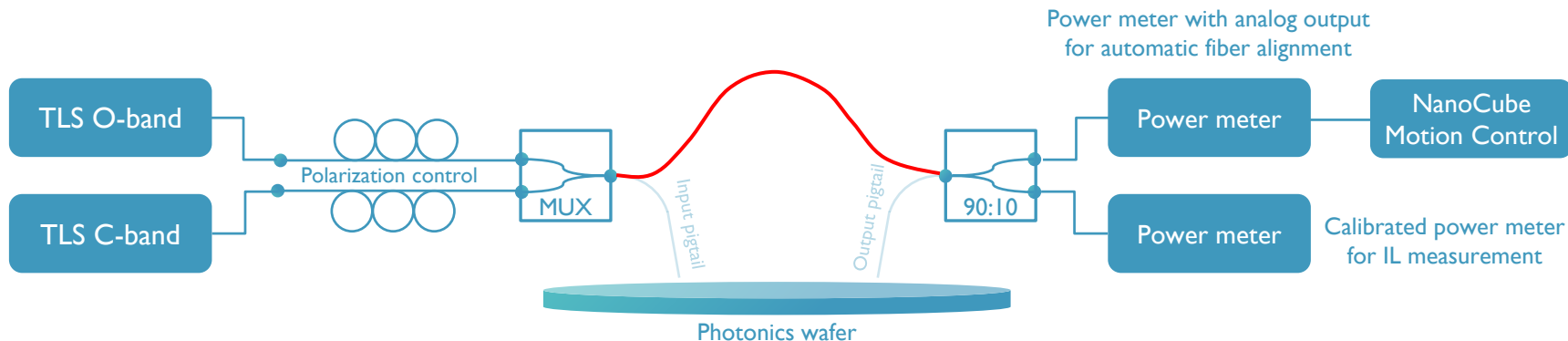
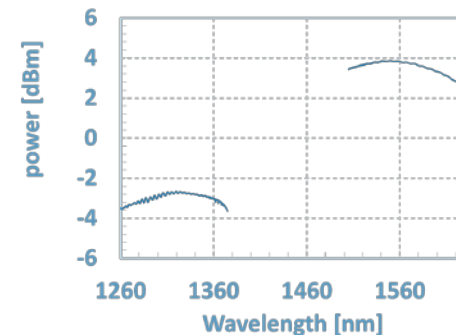
- Dual tunable laser sources O- and C-band
- All single mode fiber (SMF28)
- Measurement pigtailed with straight cleaved facets
- Nominal incidence angle 10° from vertical



INSERTION LOSS CALIBRATION

NORMALIZATION OF MEASURED LOSS SPECTRA

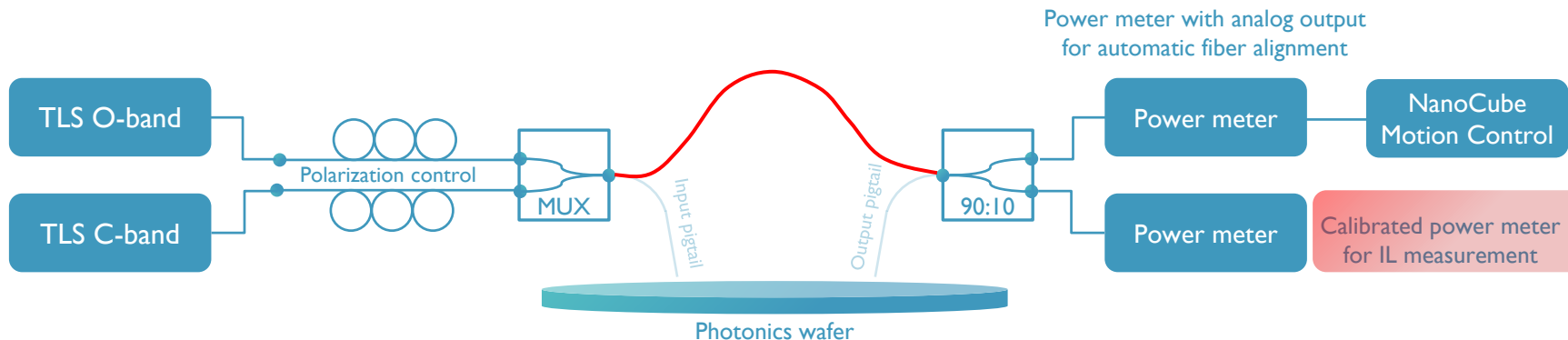
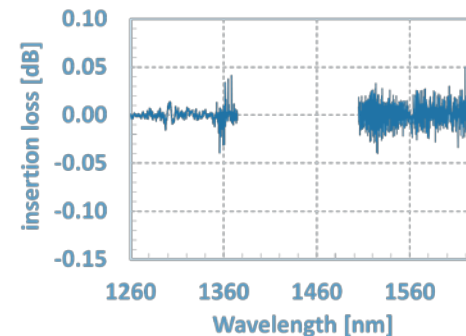
- Measurement pigtailed bypassed with a SMF28 patch cord
- Loss spectrum of components in the optical path measured over full range of TLS
- Measured spectra normalized against this spectrum



INSERTION LOSS CALIBRATION

NORMALIZATION OF MEASURED LOSS SPECTRA

- Measurement pigtailed bypassed with a SMF28 patch cord
- Loss spectrum of components in the optical path measured over full range of TLS
- Measured spectra normalized against this spectrum

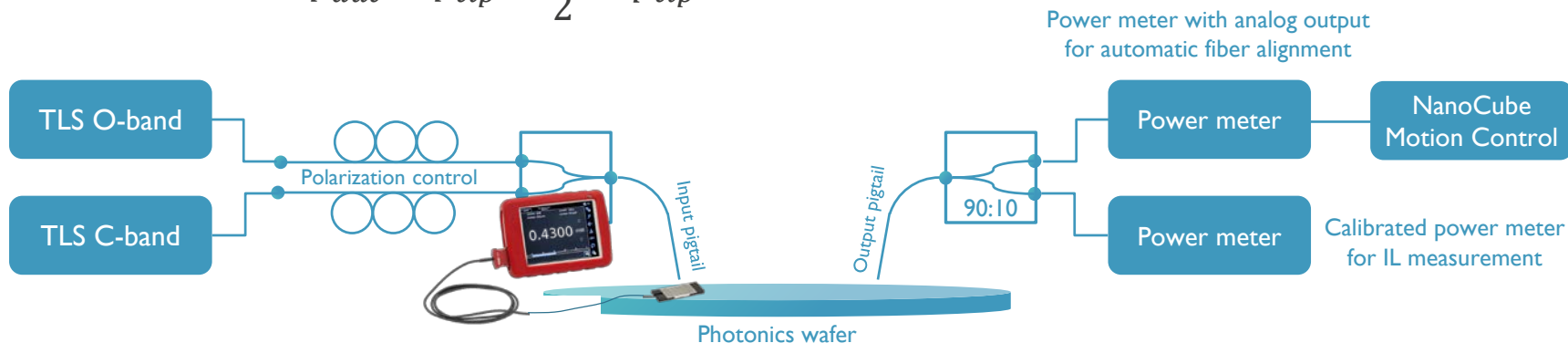


ABSOLUTE POWER CALIBRATION

INPUT PIGTAIL POWER MEASUREMENT

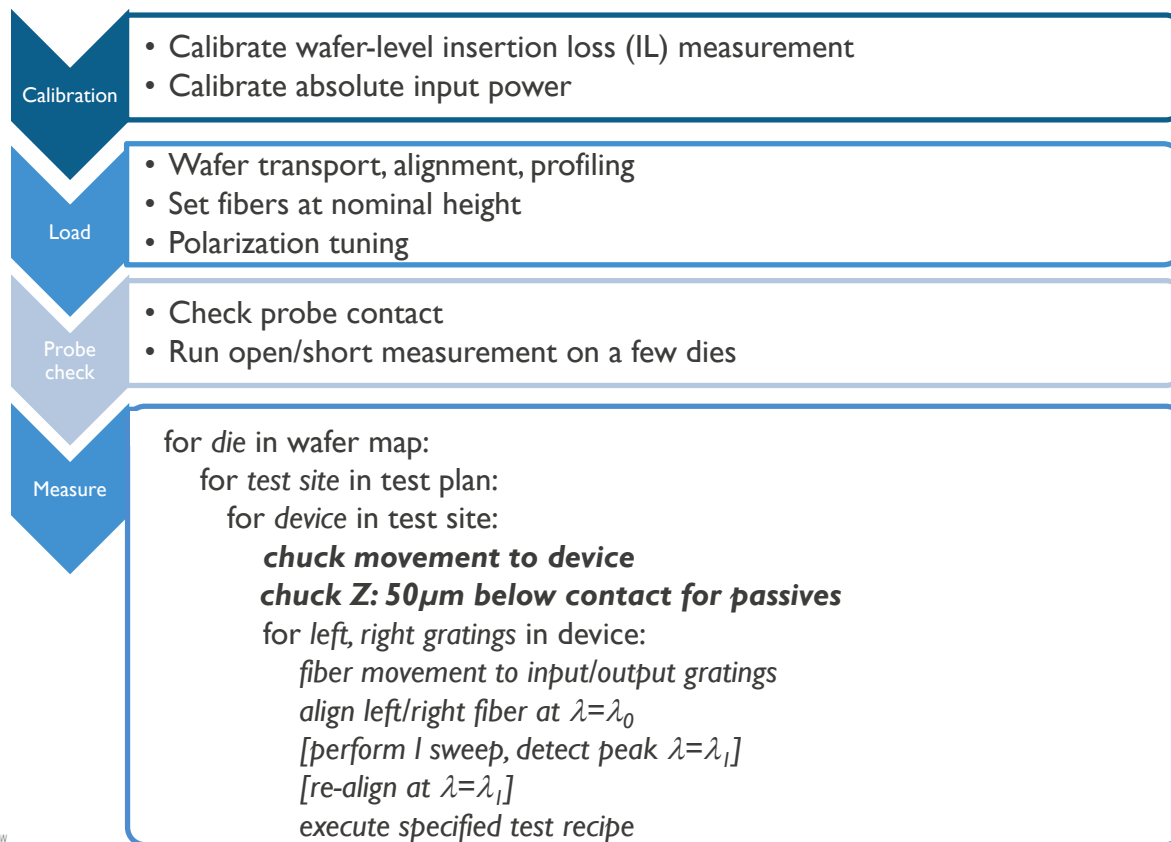
- Free-space power meter is used to measure absolute power at tip of input pigtail
- At different Ge photo diode target wavelengths
- Required to estimate power at DUT for responsivity calculation*

$$p_{dut} = p_{tip} - \frac{IL}{2} = p_{tip} - FtW IL$$

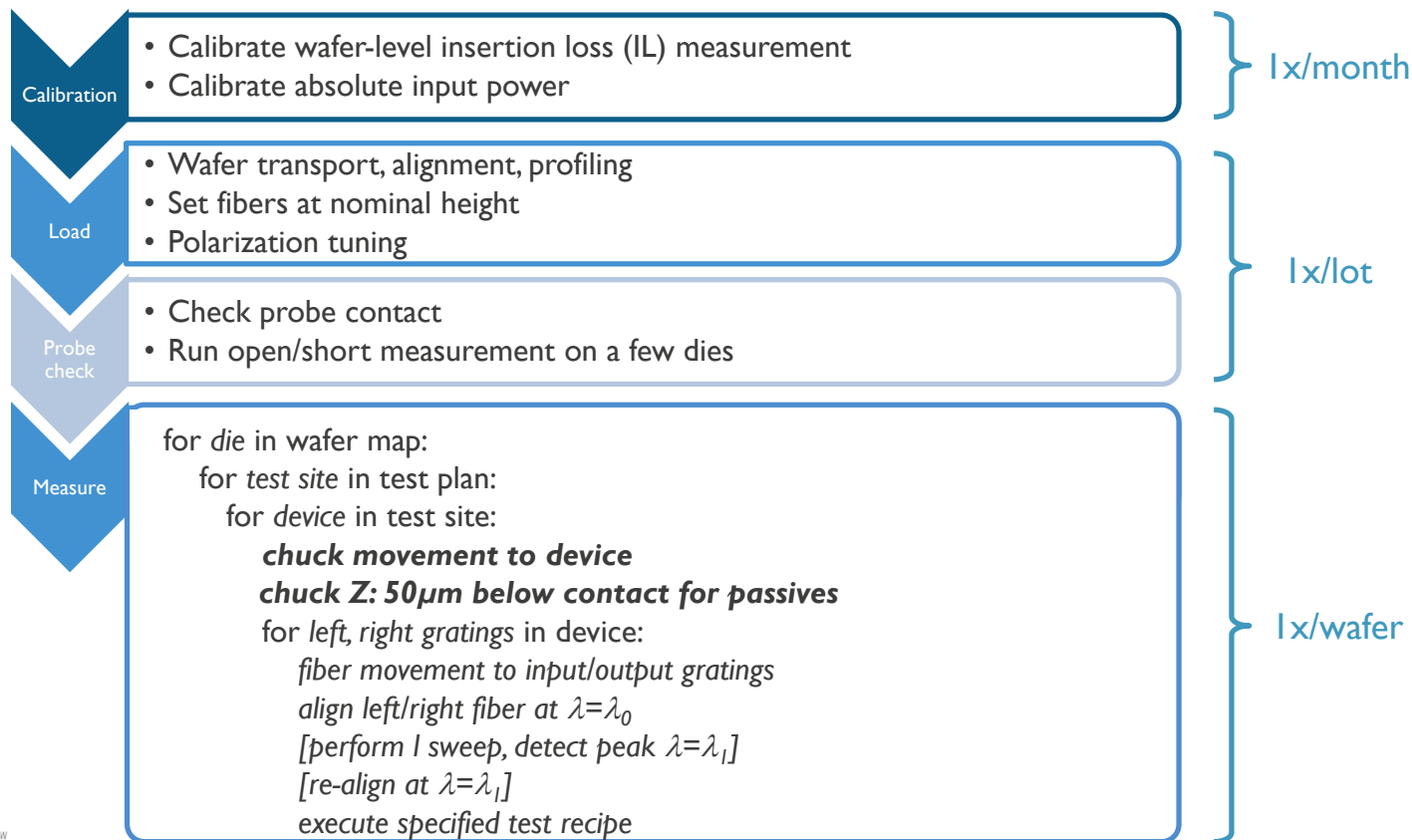


*assuming equal coupling loss at input and output pigtails

BASELINE MEASUREMENT FLOW



BASELINE MEASUREMENT FLOW



TEST EXECUTIVE SOFTWARE

- Python code, hosted on Git
- Code for test execution and data analysis & reporting
- Test plan = Python script
 - Grating coupler and probe pad coordinates pulled from XML design library
 - Settings objects defined for different built-in test recipes
 - Test plan defines a sequence of `PortCombo<Input, Output, Probe pad>` each linked with test settings object

```
<?xml version="1.0" encoding="UTF-8" standalone="no" ?>
<IODesign xmlns:py="http://codespeak.net/xml/objctify/pytype" xmlns:xsd="http://www.w3.org/2001/XMLSchema"
  xmlns:xsi="http://www.w3.org/2001/XMLSchema-instance" CreationDate="Tue Jun 13 11:08:06 2017" Designer="
  pdheyn">
  <MaskInfo MaskName="EP24"/>
  <TestSiteInfo TestSiteName="DCM_LMZC"/>
  <Notes DesignDescription="Lumped MZ modulator test structure (i.e. modulator + input and output grating
  couplers)"/>
  <DesignInfo Name="MZMCTE_LULAB_450_500">
    <LeftCouplers>
      <Coupler Name="IN" X="80.0" Y="1340.0"/>
    </LeftCouplers>
    <RightCouplers>
      <Coupler Name="OUT" X="1280.0" Y="1340.0"/>
    </RightCouplers>
    <ProbePads>
      <Coupler Name="G middle" X="717.30999999999995" Y="1340.0"/>
    </ProbePads>
  </DesignInfo>
</IODesign>
```

LOSS MEASUREMENT

DETECTOR MEASUREMENT

MODULATOR MEASUREMENT

S-PARAMETER MEASUREMENT

SParamMeasurementSetting

Properties:

Property	Description	Default value
VStart	Start voltage for S-parameter measurements	0.0V
Vspan	Voltage span for S-parameter measurements	1.0V
Vstep	Voltage resolution for S-parameter measurements	0.1V
Lpower	Laser power during S-parameter measurements	6dBm
DCBiasCompliance	Compliance of DC bias source	10mA
FStart	Start frequency for S-parameter measurements	0.0V
Fspan	Frequency span for S-parameter measurements	1.0V
FNpoints	Number of steps in frequency sweep for S-parameter measurements	
Averaging	Number of frequency sweeps to average for S-parameter measurements	
DeviceType	Component that is being tested. Determines how wavelength range is defined.	

TEST EXECUTION

OPERATING MEASUREMENT TOOL IN CLASS 1000 CLEAN ROOM

- Motivation
 - Operating the tool in a clean room allows to pull out wafers, measure, give feedback to process integration
 - Resulting in faster feedback
 - Wafers are not lost for processing, i.e. more inspections are possible
- Hence we need to verify metal/particle contamination in the tool
 - Front side particles: from clean room ambient, electrical probing
 - Front side metal contam: probing
 - Back side particles: robot arm, wafer chuck
 - Back side metal: robot arm, wafer chuck

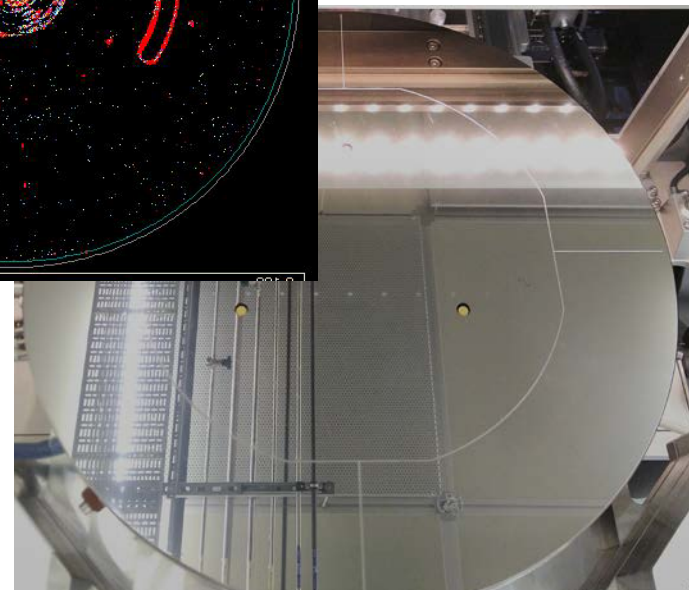
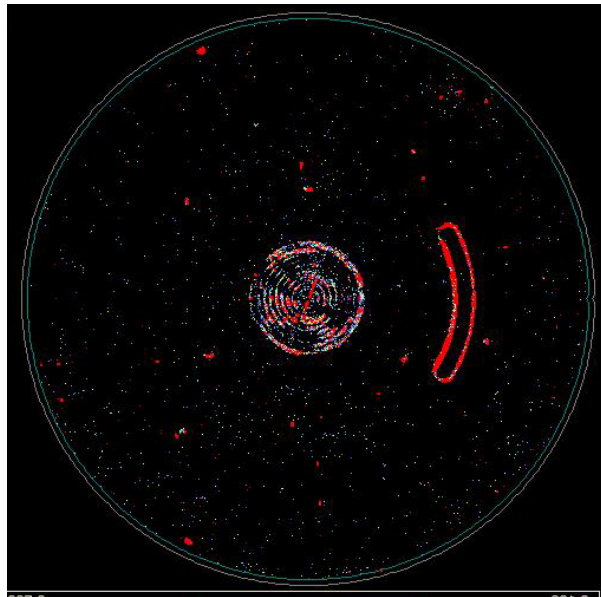
Operation in clean room

TOOL CONTAMINATION STATUS

BACKSIDE PARTICLE MEASUREMENT

- Typical witness wafer work flow
 - Front-side particle measurement
 - Wafer flip
 - Go through normal load/unload cycle on tool
 - Wafer flip
 - Front-side particle measurement

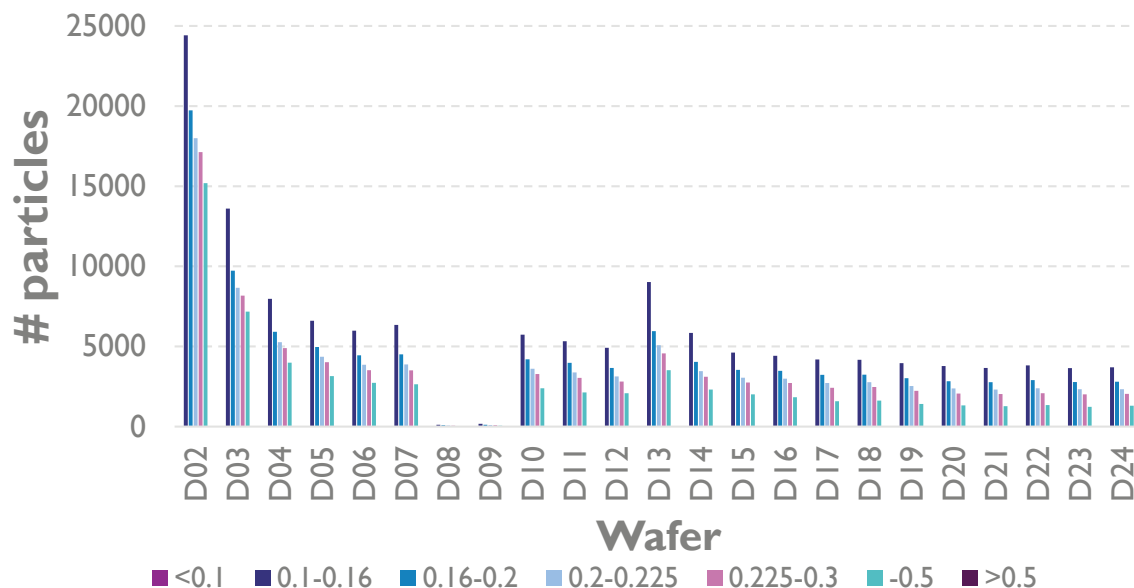
- Visible marks of robot arm, pre-aligner, chuck lift pins



BACKSIDE PARTICLE MEASUREMENT

VERIFICATION OF CLEANING PROCEDURE

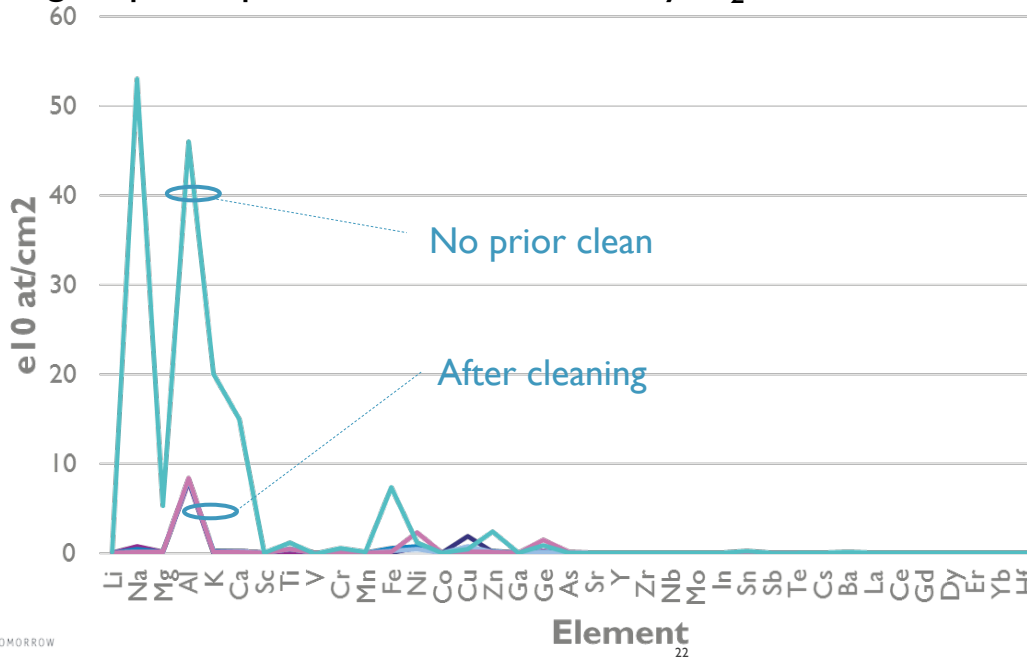
- Initial tool status: measured ~100 level 5 wafers
- No cleaning done before loading witness wafers
- After 10 wafers, particle count drop below spec limit for target contamination level 3
- Chuck cleaned with IPA after wafer 12
- Then loaded wafers 13-24
- Particle count stabilized after another 3-4 wafers



BACKSIDE METAL CONTAMINATION – TXRF MEASUREMENT

VERIFICATION OF CLEANING PROCEDURE

- Measurement without and with cleaning step prior to cycling witness wafer
 - Initial tool status: level 3
 - Cleaning step - wipe with IPA and blow dry N₂

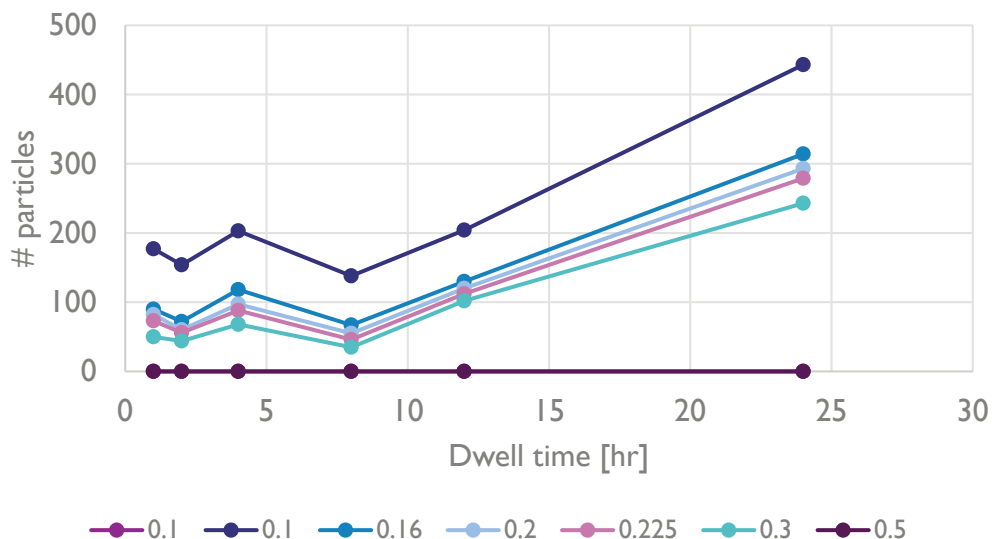


DuploWaferId	Element	Conc	WL	SL
D03	Li	0.04	10	100
D03	Na	0.8	100	999918
D03	Mg	0.15	100	999916
D03	Al	8	100	999907
D03	K	0.068	9999999	9999994
D03	Ca	0.24	9999999	9999992
D03	Sc	0.0037	10	100
D03	Ti	0.078	100	999924
D03	V	-4.00E-06	100	999925
D03	Cr	0.035	10	100
D03	Mn	0.0014	10	100
D03	Fe	0.08	10	50
D03	Ni	0.59	10	100
D03	Co	0.0016	10	100
D03	Cu	0.2	10	100
D03	Zn	0.11	10	100
D03	Ga	0.00044	100	999910
D03	Ge	0.19	100	9999998
D03	As	0.042	100	999908

FRONT SIDE PARTICLE MEASUREMENT

VERIFICATION OF PROBING AND AMBIENT

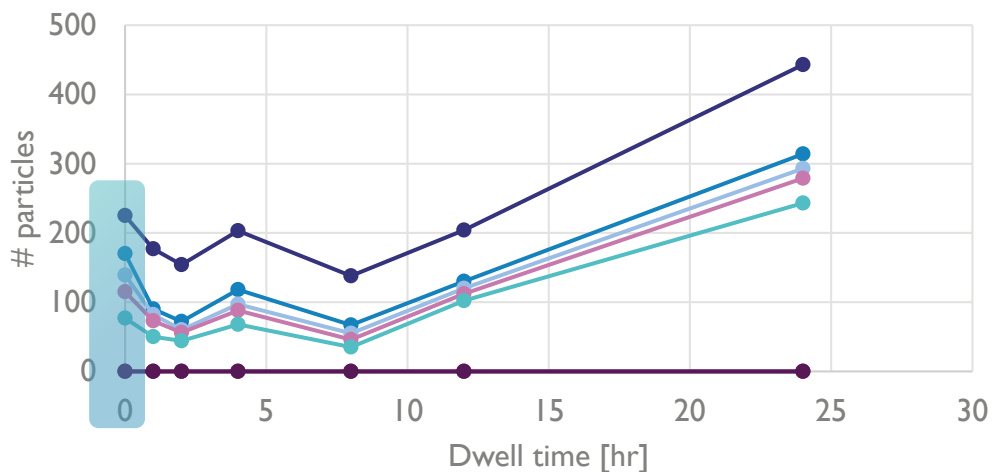
- Experiment #1: variable wafer dwell time on chuck: 1-2-4-8-12-24 hours
 - Only for dwell times > 10h, clear relationship between dwell time and #particles



FRONT SIDE PARTICLE MEASUREMENT

VERIFICATION OF PROBING AND AMBIENT

- Experiment #1: variable wafer dwell time on chuck: 1-2-4-8-12-24 hours
 - Only for dwell times > 10h, clear relationship between dwell time and #particles
- Experiment #2: probe touchdowns



—●— 0.1 —●— 0.1 —●— 0.16 —●— 0.2 —●— 0.225 —●— 0.3 —●— 0.5

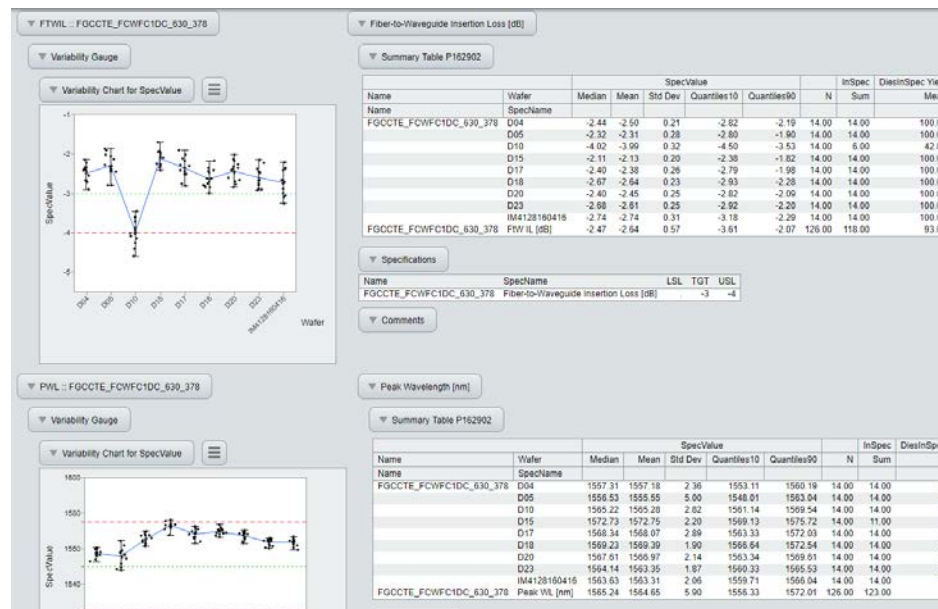
AUTOMATED DATA ANALYSIS

ANALYSIS WORK FLOW

- Python code in Git repository for data analysis
- Automation:
 - `oio_pyro_service`: Pyro 4 (Python remote objects) daemon encapsulated in a windows service (defined using `win32serviceutil` module) which exposes a number of analysis methods
 - `oio_email_service`: a windows service that encapsulates an email client; e-mail used to trigger analysis/report generation for a specified lot/wafer/...
 - Windows task scheduler to scan network folders for new data and automatically generate reports overnight
 - XML file meta data is used to select analysis method

AUTOMATED DATA ANALYSIS REPORTING

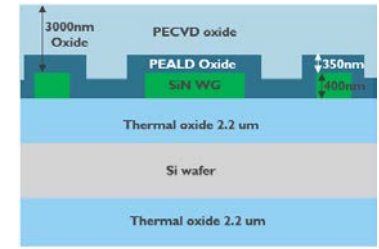
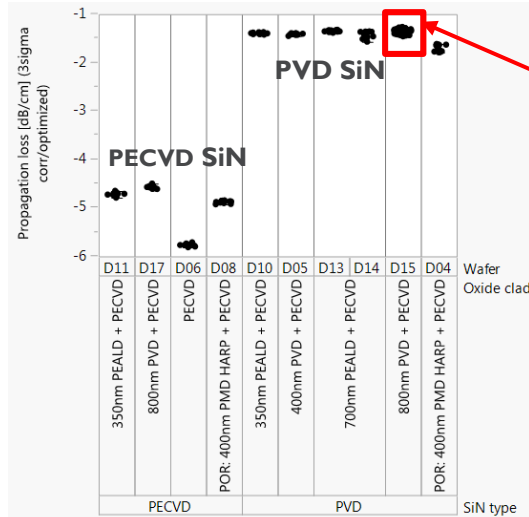
- Output:
 - 1 csv file per lot and per component class
 - loss, photodiode, modulator, mmi, dc, ...
 - Aggregated data table with all components
 - Aggregated data table including wafer statistics and spec check
 - Target, USL and LSL defined per component/parameter and project
 - HTML report
 - Results are also consolidated per component type across different lots



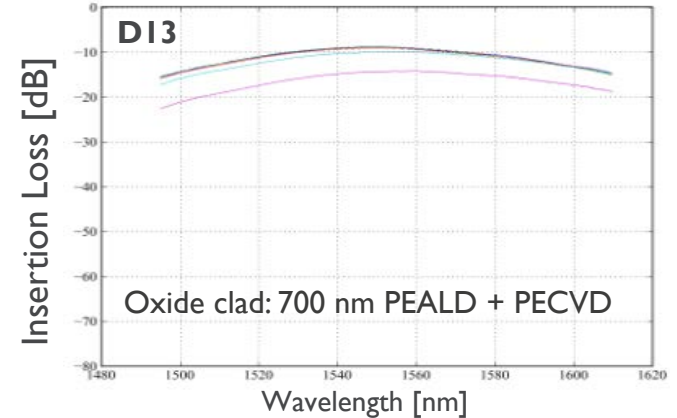
SiN WG PROPAGATION LOSS

MEASURED PROPAGATION LOSS AT 1520NM WAVELENGTH

Waveguide propagation loss at 1520nm
W= 840nm, TE Polarization



PVD/PECVD SiN WG on Si wafer



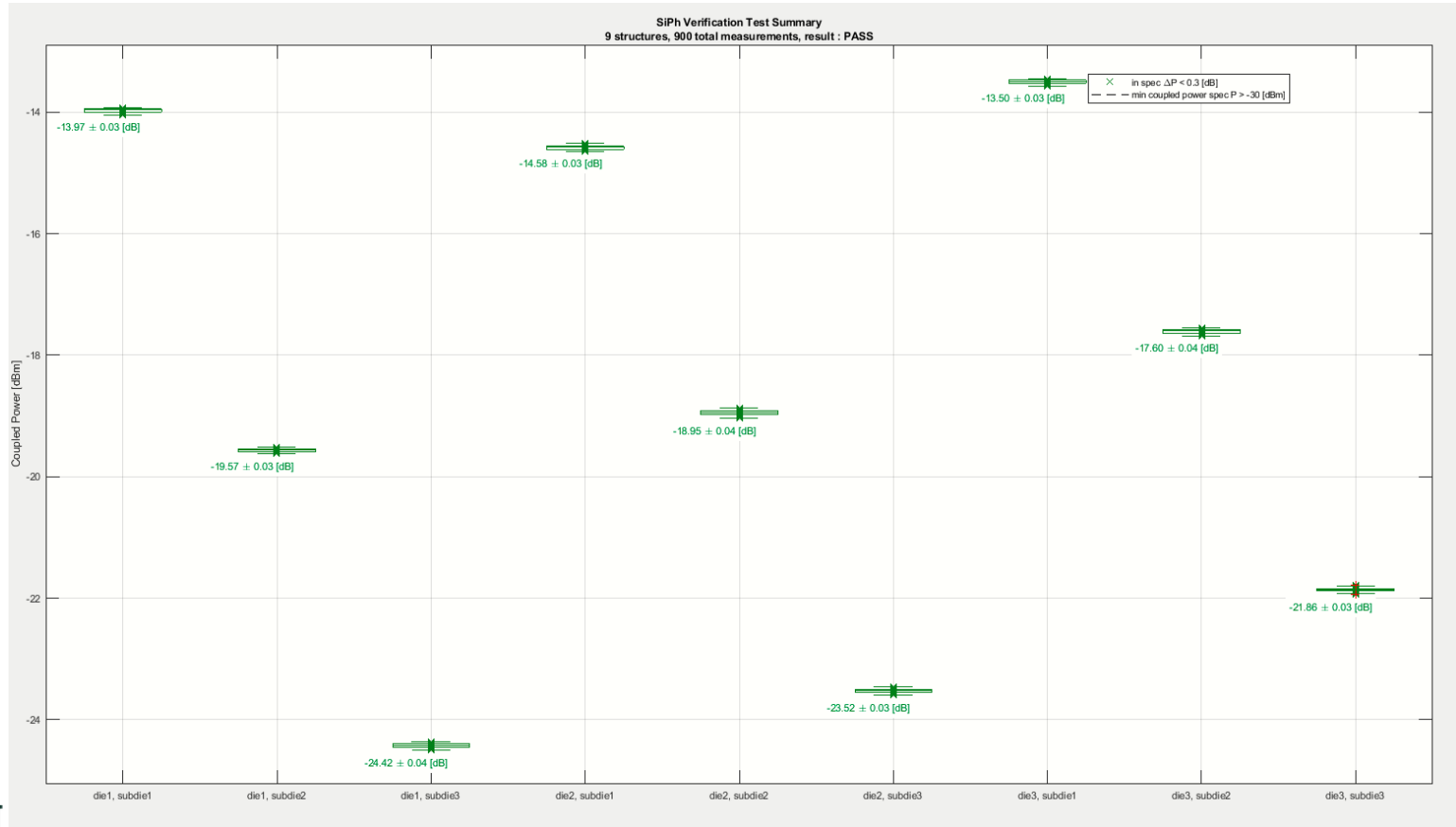
SiN type	Oxide clad	Wafer	Propagation loss [dB/cm] (3sigma corr/optimized)						
			Mean	Std Dev	Min	Max	Quantiles90	Quantiles10	N
PECVD	350nm PEALD + PECVD	D11	-4.72	0.03	-4.79	-4.65	-4.67	-4.77	15.00
	800nm PVD + PECVD	D17	-4.57	0.03	-4.61	-4.50	-4.51	-4.60	15.00
	PECVD	D06	-5.77	0.02	-5.81	-5.71	-5.72	-5.80	15.00
	POR: 400nm PMD HARP + PECVD	D08	-4.88	0.02	-4.92	-4.84	-4.85	-4.92	15.00
PVD	350nm PEALD + PECVD	D10	-1.40	0.02	-1.42	-1.37	-1.37	-1.42	14.00
	400nm PVD + PECVD	D05	-1.41	0.02	-1.45	-1.39	-1.39	-1.44	14.00
	700nm PEALD + PECVD	D13	-1.35	0.02	-1.38	-1.32	-1.32	-1.38	14.00
		D14	-1.43	0.07	-1.57	-1.35	-1.36	-1.53	15.00
	800nm PVD + PECVD	D15	-1.34	0.04	-1.46	-1.26	-1.30	-1.41	100.00
	POR: 400nm PMD HARP + PECVD	D04	-1.70	0.07	-1.79	-1.62	-1.62	-1.79	13.00

Propagation loss at 1520 nm:

- Last PTW : 4.9dB/cm

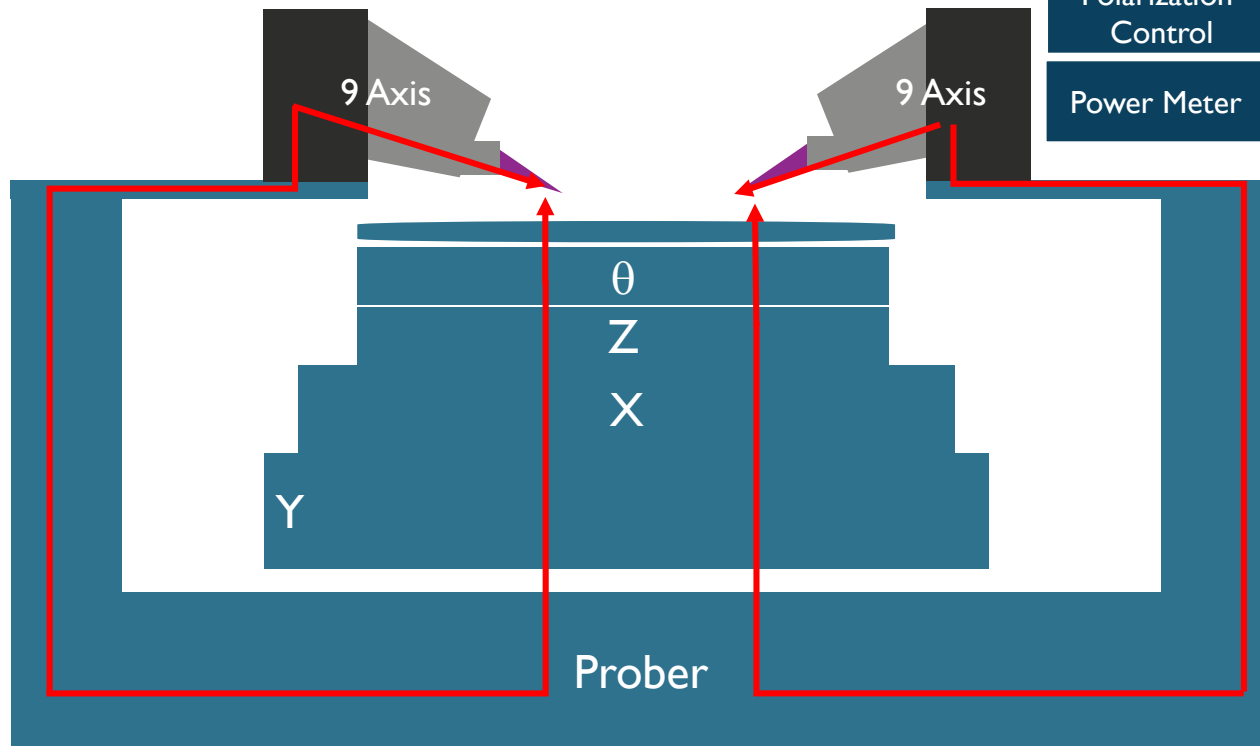
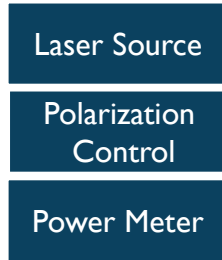
- **Now : 1.34 dB/cm**

<.3 dB COUPLED POWER REPEATABILITY



SYSTEM LEVEL CHALLENGE

THE SUBSYSTEMS THAT NEED TO COME TOGETHER TO ACHIEVE THIS MEASUREMENT PERFORMANCE:



- ~1m Kinematic Loop
 - Fiber Tip / Z Displacement Sensor
 - 9 DOF of two positioners (18 Axis)
 - Prober platen and Base
 - XYZ and Theta chuck stack
 - Wafer
- Components
 - Laser Source
 - Polarization control
 - Power Meter
- Characteristics needed to achieve:
 - Stable kinematic loop
 - Positioning calibrated to Probe Station
 - Well tuned servo control
 - Optimized scanning motion
 - Stable input power and polarization
 - Stable environment

MEASUREMENT REPEATABILITY

LOSS MEASUREMENT ON 2 WAFERS

- Measurement sequence:

20x

- Transport first wafer from cassette to pre-aligner
- Rotate wafer at 87 deg
- Transport wafer to ID reader
- Read ID
- Transport wafer to pre-aligner
- Align wafer to 88.53 deg
- Transport wafer to prober
- Auto-align the wafer
- Perform a Z profiling of the wafer (using autofocus on 7 dies)
- Set chuck and fiber home position
- Perform a loss measurement on 13 dies (5 spirals, LR fiber alignment on each spiral)
- When measurement finishes, return fibers to home position
- Transport wafer from prober to cassette
- Repeat above steps for all remaining wafers in the cassette (only two wafers in this experiment)

MEASUREMENT REPEATABILITY

LOSS MEASUREMENT ON 2 WAFERS

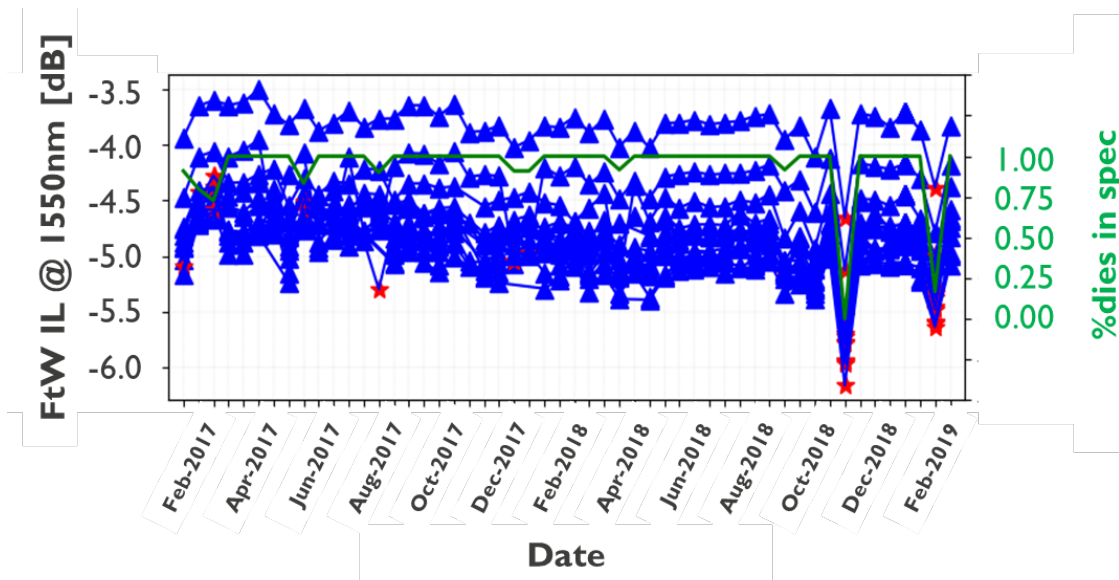
Wafer		(0,0)	(0,2)	(-1,-2)	(2,1)	(-2,2)	(2,-3)	(-3,0)	(3,-1)	(4,-2)	(-4,2)	(-4,-3)	(5,0)	(-5,-1)	StdDev/Mean	
D05	Propagation loss [dB/cm]	Mean	-1.83	-1.8	-1.74	-1.79	-1.8	-4.81	-1.79	-1.78	-2.03	-1.86	-7.16	-1.76	-3.27	-2.570769231
		Std Dev	0.0042	0.0048	0.0044	0.0059	0.01	0.0428	0.0041	0.0051	0.006	0.0064	0.0532	0.0063	0.0109	0.012623077
		N	20	20	20	20	19	20	20	20	20	20	20	20	20	
	FtW IL [dB]	Mean	-5.25	-5.25	-5.21	-5.25	-5.25	-5.8	-5.28	-5.18	-5.29	-5.28	-11.3	-5.23	-5.7	-5.79
		Std Dev	0.0159	0.0159	0.0149	0.0161	0.0291	0.0238	0.0113	0.0151	0.0143	0.0129	0.02	0.0241	0.0112	0.017276923
		N	20	20	20	20	19	20	20	20	20	20	20	20	20	
	Peak WL [nm]	Mean	1553	1552	1551	1553	1551	1554	1551	1553	1553	1549	1564	1552	1551	1552.846154
		Std Dev	0.0839	0.0717	0.0785	0.0822	0.0858	0.097	0.0818	0.0717	0.0785	0.0632	0.0754	0.0959	0.0822	0.0806
		N	20	20	20	20	19	20	20	20	20	20	20	20	20	
	FtW IdB BW [nm]	Mean	33.16	34.13	33.97	33.39	34.3	33.75	34.07	33.54	33.35	34.77	36.54	33.31	34.23	34.03923077
		Std Dev	0.0941	0.1027	0.0717	0.1053	0.0996	0.0822	0.0822	0.0839	0.052	0.0886	0.0717	0.0882	0.0822	0.084953846
		N	20	20	20	20	19	20	20	20	20	20	20	20	20	
D14	Propagation loss [dB/cm]	Mean	-2.16	-2.12	-2.12	-2.16	-2.24	-4.07	-2.11	-2.09	-2.09	-2.21	-6.67	-1.97	-2.36	-2.643846154
		Std Dev	0.0089	0.0092	0.006	0.0059	0.0061	0.0088	0.0083	0.0072	0.009	0.0131	0.0152	0.0183	0.0035	0.009192308
		N	19	19	19	19	19	19	19	19	19	19	19	19	19	
	FtW IL [dB]	Mean	-5.62	-5.66	-5.63	-5.66	-5.68	-5.86	-5.72	-5.58	-5.63	-5.7	-12.7	-5.59	-5.72	-6.211538462
		Std Dev	0.0264	0.0117	0.0116	0.0137	0.0116	0.0177	0.0233	0.0142	0.024	0.0146	0.0213	0.02	0.0147	0.017292308
		N	19	19	19	19	19	19	19	19	19	19	19	19	19	
	Peak WL [nm]	Mean	1542	1539	1539	1542	1539	1541	1539	1541	1540	1537	1555	1540	1538	1540.923077
		Std Dev	0.0804	0.0795	0.0505	0.0795	0.0981	0.1047	0.0901	0.1182	0.0901	0.0813	0.0795	0.0996	0.0766	0.086776923
		N	19	19	19	19	19	19	19	19	19	19	19	19	19	
	FtW IdB BW [nm]	Mean	36.06	37.39	37.21	36.81	37.58	37.2	37.07	36.81	36.6	38.29	40.29	36.55	37.85	37.36230769
		Std Dev	0.0996	0.1011	0.1055	0.0958	0.111	0.0841	0.1011	0.1097	0.1047	0.0804	0.0766	0.1069	0.0736	0.096161538
		N	19	19	19	19	19	19	19	19	19	19	19	19	19	



MEASUREMENT REPRODUCIBILITY

REFERENCE WAFER MEASUREMENTS

- Repeated measurement of same wafer/dies/structures, ~bi-weekly interval
- Evolution of 8 device parameters tracked
 - FtW IL, TE/TM, C/O band
 - Photo diode responsivity
 - Photo diode dark current
- Also implemented Western Electric rules



MEASUREMENT REPRODUCIBILITY

REFERENCE WAFER MEASUREMENTS

- Corrective actions taken when required

Symptom	Possible cause	Corrective action
Id too low	Bad probe contact	Adjust probe overtravel
		Clean probe tips
FtW IL out of spec	Incorrect fiber height	Adjust fiber height
	Fiber facet not clean	Clean fiber facet
	Polarization not well calibrated	Calibrate input SOP
	Fiber facet damaged	Replace measurement pigtail
	Setup loss not well calibrated	Calibrate setup loss
Responsivity out of spec and FtW IL is also out of spec	First solve issue with FtW IL	See steps above
Responsivity out of spec but FtW IL is in spec	Imbalance between input and output pigtail FtW IL	Poor calibration of pigtail output power
		Check if input and output pigtails are at same height

MEASUREMENT REPRODUCIBILITY

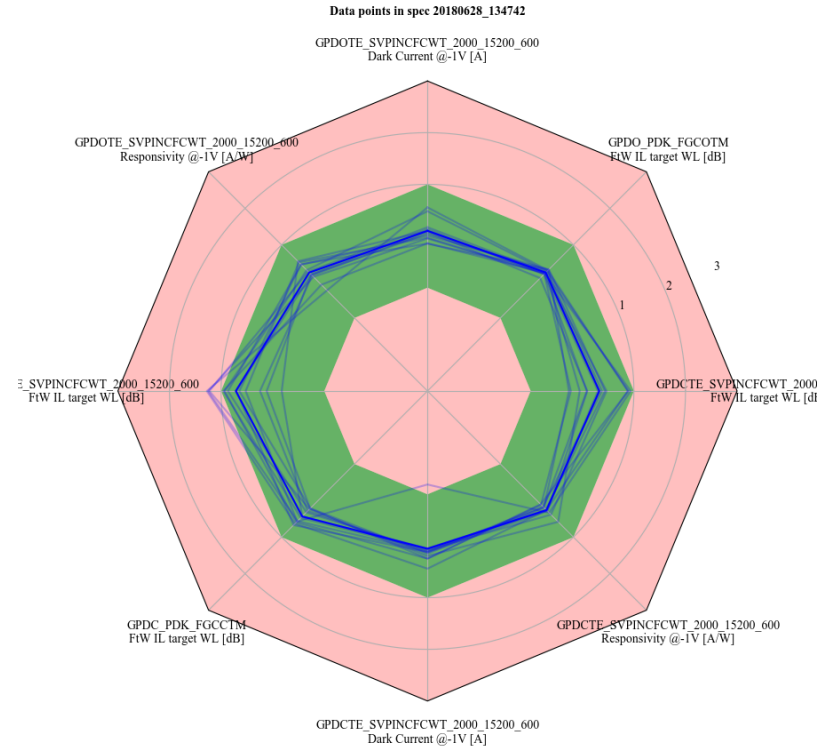
REFERENCE WAFER MEASUREMENTS

■ Data analysis

- Target value for each die/device/parameter defined as average of past measurements
- Each data point is normalized as (i-th observation of quantity x_i)

$$p_{ji} = \frac{x_{ji} - \mu_i}{\sigma_i}$$

- For each die, parameters p_j ($j=1\dots 8$) are plotted on a radar plot
- Green zone is $\pm 1\sigma$
- Bold blue line = wafer average



CONCLUSION

- Running PCM measurements in clean room enables faster feedback to process integration engineers
 - Enables checking process changes in-line to tune parameters
- Inline measurements require a fully automated tool - FormFactor CM300xi-SiPh
- Calibration procedures are in place to ensure accuracy of measured parameters
- Dual use case of measurement data
 - Ensure technology-specific device parameters are meeting PDK specifications
 - Validating the effect of process/design changes on those structures
- Contamination analysis verifies that the tool operates within cleanroom specification
 - Tool is not a source of contamination
- Test Setup Monitoring is used to demonstrate the tool is providing repeatable and reproducible measurements



SWTEST

PROBE TODAY, FOR TOMORROW

THANKS FOR YOUR ATTENTION



FORMFACTOR™

mecc

June 2-5, 2019

PUBLIC